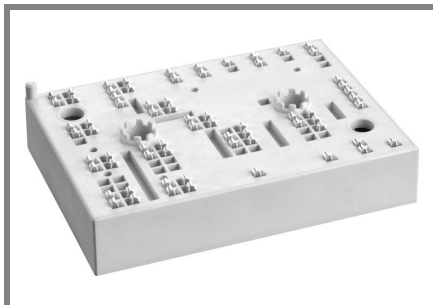


SKiiP 35NAB12T4V1



MiniSKiiP® 3

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 35NAB12T4V1

Features

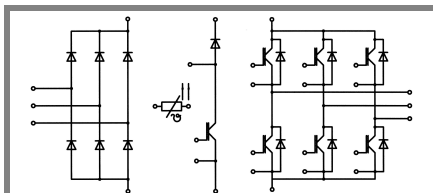
- Trench 4 IGBT's
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 26 kVA
- Typical motor power 15 kW

Remarks

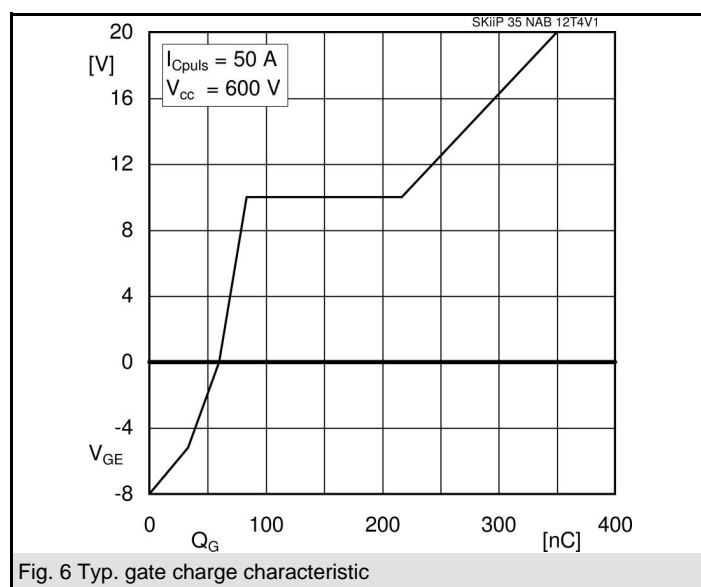
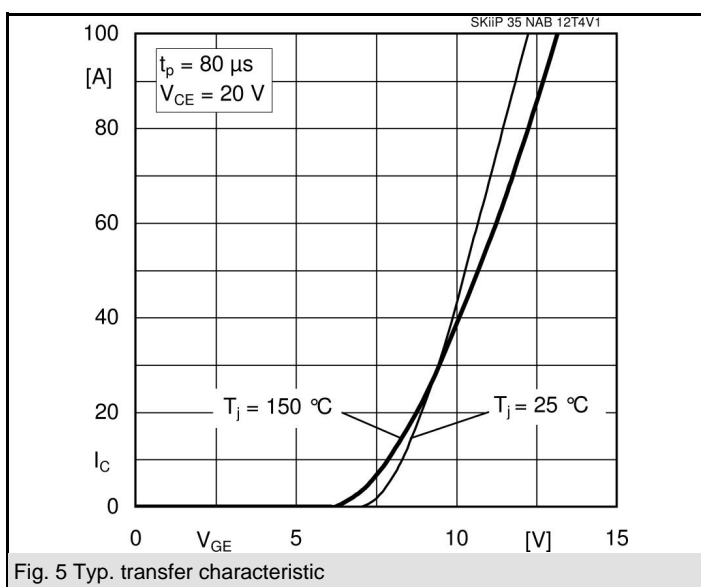
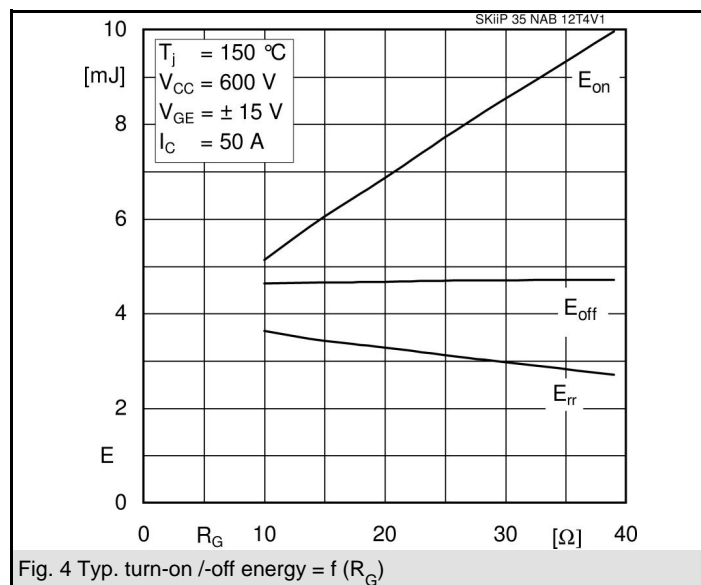
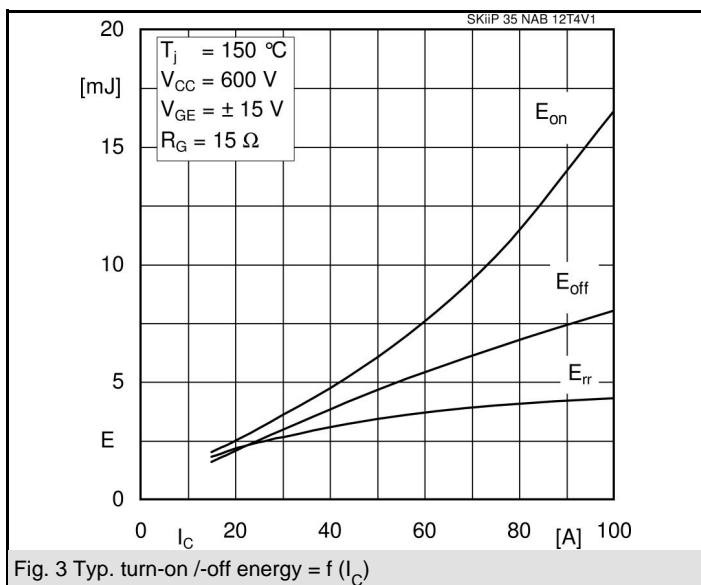
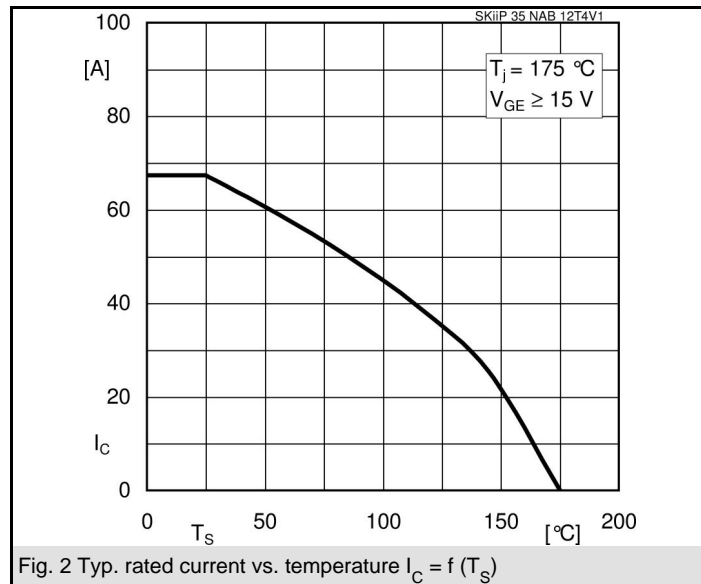
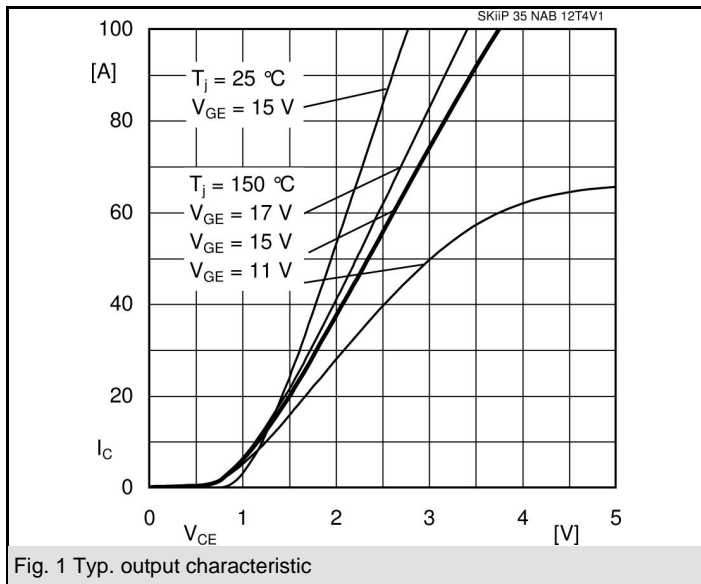
- V_{CEsat} , V_F = chip level value
- Case temp. limited to $T_C = 125^\circ\text{C}$ max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_{j \leq 150}$ (recomm. $T_{op} = -40 \dots +150^\circ\text{C}$)

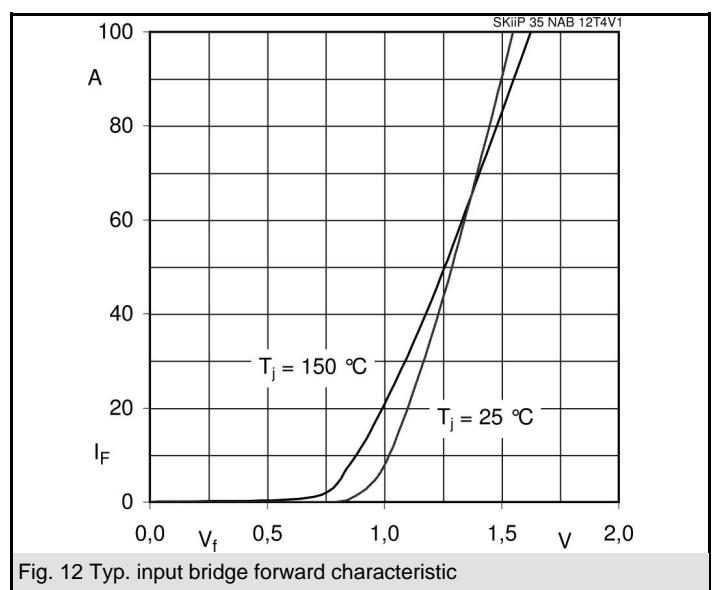
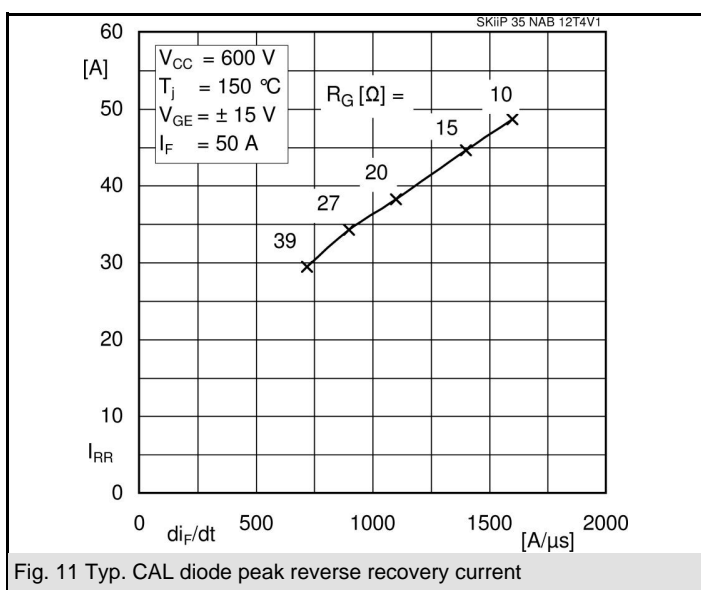
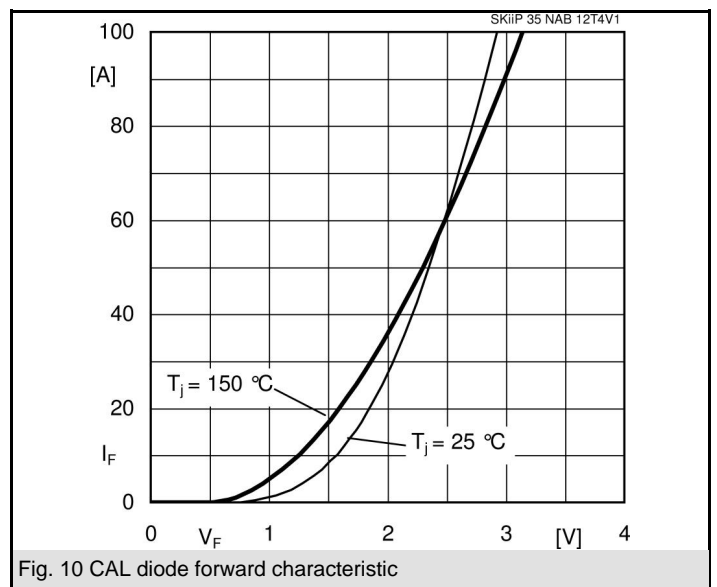
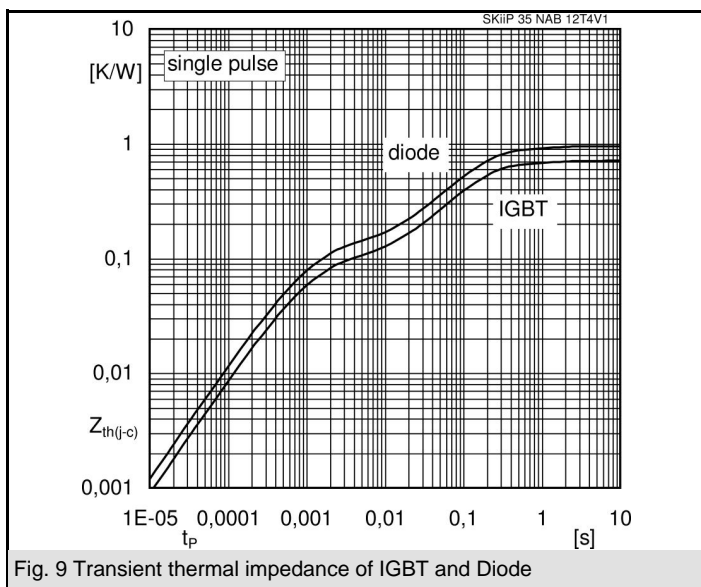
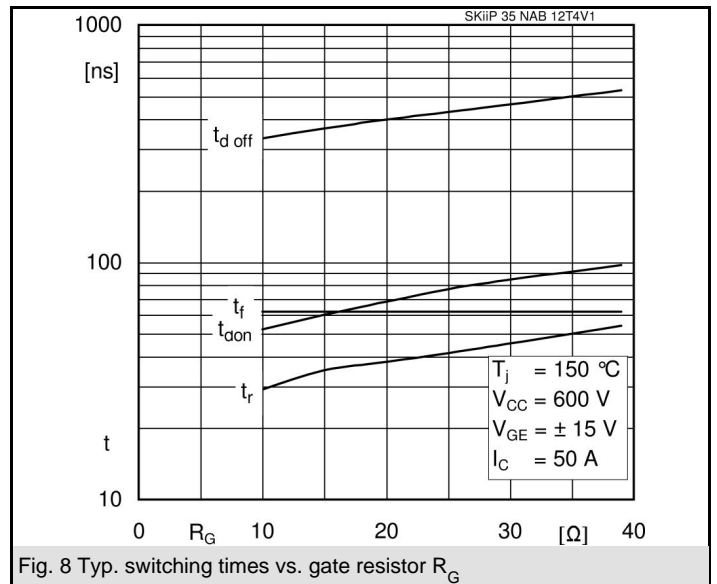
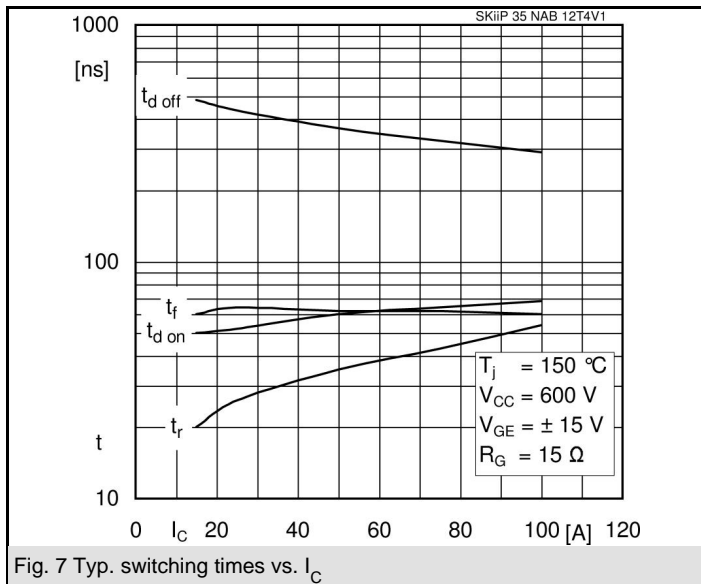


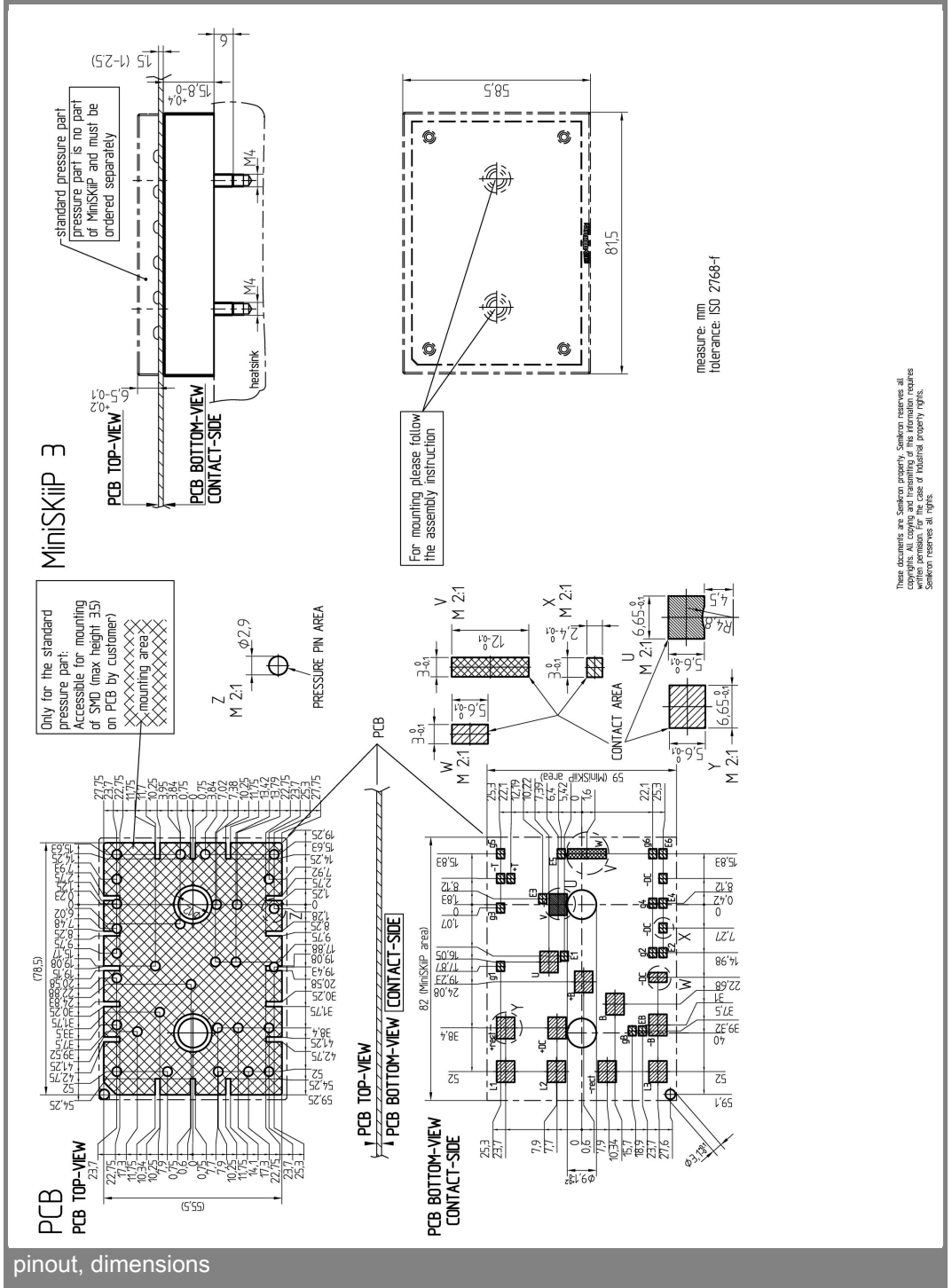
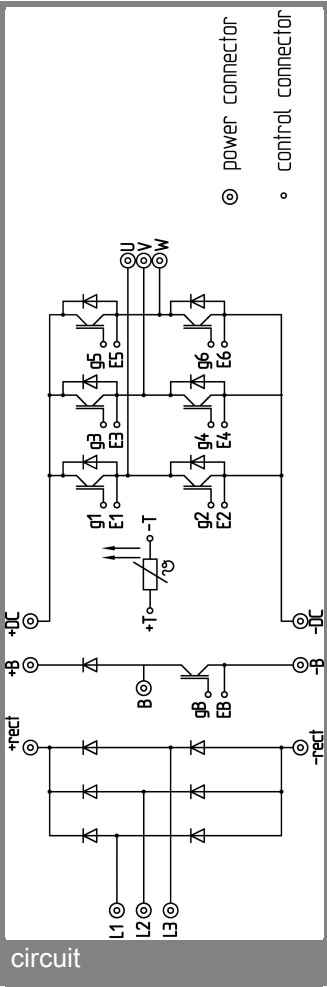
NAB

Absolute Maximum Ratings		$T_S = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values	Units	
IGBT - Inverter, Chopper				
V_{CES}	$T_S = 25 (70)^\circ\text{C}$	1200	V	
I_C		67 (52)	A	
I_{CRM}		150	A	
V_{GES}		± 20	V	
T_j		- 40 ... + 175	$^\circ\text{C}$	
Diode - Inverter, Chopper				
I_F	$T_S = 25 (70)^\circ\text{C}$	60 (48)	A	
I_{FRM}		150	A	
T_j		- 40 ... + 175	$^\circ\text{C}$	
Diode - Rectifier				
V_{RRM}	$T_S = 70^\circ\text{C}$	1600	V	
I_F		61	A	
I_{FSM}		$t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$	700	A
i^2t		$t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$	2400	A^2s
T_j		- 40 ... + 150	$^\circ\text{C}$	
Module				
I_{RMS}	per power terminal (20 A / spring)	80	A	
T_{stg}		- 40 ... + 125	$^\circ\text{C}$	
V_{isol}	AC, 1 min.	2500	V	

Characteristics		$T_S = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
V_{CEsat}	$I_{Cnom} = 50 \text{ A}, T_j = 25 (150)^\circ\text{C}$		1,85 (2,25)	2,05 (2,45)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 2 \text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25 (150)^\circ\text{C}$		0,8 (0,7)	0,9 (0,8)	V
r_T	$T_j = 25 (150)^\circ\text{C}$		21 (31)	23 (33)	m Ω
C_{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		2,77		nF
C_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,21		nF
C_{res}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,16		nF
$R_{th(j-s)}$	per IGBT		0,71		K/W
$t_{d(on)}$	under following conditions		60		ns
t_r	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		35		ns
$t_{d(off)}$	$I_{Cnom} = 50 \text{ A}, T_j = 150^\circ\text{C}$		370		ns
t_f	$R_{Gon} = R_{Goff} = 15 \Omega$		60		ns
E_{on}	inductive load		6		mJ
E_{off}			4,7		mJ
Diode - Inverter, Chopper					
$V_F = V_{EC}$	$I_{Fnom} = 50 \text{ A}, T_j = 25 (150)^\circ\text{C}$		2,25 (2,2)	2,55 (2,5)	V
$V_{(TO)}$	$T_j = 25 (150)^\circ\text{C}$		1,3 (0,9)	1,5 (1,1)	V
r_T	$T_j = 25 (150)^\circ\text{C}$		19 (26)	21 (28)	m Ω
$R_{th(j-s)}$	per diode		0,95		K/W
I_{RRM}	under following conditions		45		A
Q_{rr}	$I_{Fnom} = 50 \text{ A}, V_R = 600 \text{ V}$		8,6		μC
E_{rr}	$V_{GE} = 0 \text{ V}, T_j = 150^\circ\text{C}$		3,4		mJ
	$di_F/dt = 1400 \text{ A}/\mu\text{s}$				
Diode - Rectifier					
V_F	$I_{Fnom} = 35 \text{ A}, T_j = 25^\circ\text{C}$		1,1		V
$V_{(TO)}$	$T_j = 150^\circ\text{C}$		0,8		V
r_T	$T_j = 150^\circ\text{C}$		11		m Ω
$R_{th(j-s)}$	per diode		0,9		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25 (100)^\circ\text{C}$		1000(1670)		Ω
Mechanical Data					
w			95		g
M_s	Mounting torque	2		2,5	Nm







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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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